

描述 / Descriptions

PDFN 5×6 封装 N 沟道场效应管。

N-Channel MOSFET in a PDFN 5×6 Plastic Package .

特征 / Features

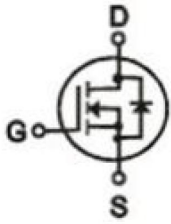
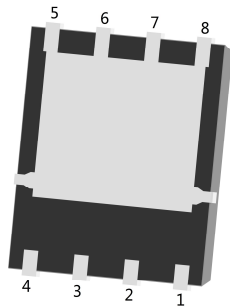
低电阻可最大地降低导电损耗；低栅极电荷，可实现快速切换；低热阻；无卤产品。

Low $R_{DS(ON)}$ to minimize conductive loss; low Gate Charge for fast switching; Low Thermal resistance; HF Product.

用途 / Applications

高频开关和同步整流，DC 电机驱动器

High Frequency Switching and Synchronous Rectification, DC-Motor Driver

内部等效电路 / Equivalent Circuit**引脚排列 / Pinning**

PIN1、2、3: S

PIN4: G

PIN5、6、7、8: D

Pin	极性
1	S
2	S
3	S
4	G
5	D
6	D
7	D
8	D

印章代码 / Marking

见印章说明。See Marking Instructions.

极限参数 / Absolute Maximum Ratings($T_a=25^{\circ}\text{C}$)

参数 Parameter		符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage		V _{DSS}	40	V
Drain Current		I _D (Tc=25°C)	52	A
Drain Current - Pulsed		I _{DM}	110	A
Gate-Source Voltage		V _{GS}	±20	V
Single Pulsed Avalanche Energy		E _{AS}	67.6	mJ
Avalanche Current		I _{AS}	13	A
Power Dissipation		P _D (Tc=25°C)	36.5	W
Operating and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C
Thermal resistance, junction - ambient	t ≤ 10s	R _{θJA}	20	°C/ W
	Steady-State		55	
Thermal resistance, junction - case	Steady-State	R _{θJC}	3.4	

电性能参数 / Electrical Characteristics($T_a=25^{\circ}\text{C}$)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}$ $I_{\text{D}}=250\mu\text{A}$	40	47		V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=40\text{V}$ $V_{\text{GS}}=0\text{V}$			1	μA
Gate-Body Leakage Current Forward	I_{GSS}	$V_{\text{GS}}=\pm 20\text{V}$ $V_{\text{DS}}=0\text{V}$			± 0.1	μA
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}$ $I_{\text{D}}=250\mu\text{A}$	1.0	1.6	2.5	V
Static Drain-Source On-Resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}}=10\text{V}$ $I_{\text{D}}=20\text{A}$		6.4	8	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}$ $I_{\text{D}}=10\text{A}$		10	13	$\text{m}\Omega$
Drain-Source Diode Forward Voltage	V_{SD}	$V_{\text{GS}}=0\text{V}$ $I_{\text{S}}=1\text{A}$			1.2	V
Input Capacitance	C_{iSS}	$V_{\text{DS}}=25\text{V}$ $V_{\text{GS}}=0\text{V}$ $f=1.0\text{MHz}$		850		pF
Output Capacitance	C_{oSS}			115		
Reverse Transfer Capacitance	C_{rSS}			30		
Gate resistance	R_{g}	$V_{\text{GS}}=0\text{V}$ $V_{\text{DS}}=0\text{V}$ $f=1\text{MHz}$		2.4		Ω

电性能参数 / Electrical Characteristics(Ta=25°C)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Total Gate Charge	$Q_{g(10V)}$	$V_{GS}=10V$ $V_{DS}=20V$ $I_D=20A$		21		nC
Total Gate Charge	$Q_{g(4.5V)}$			8.8		
Gate Source Charge	Q_{gs}			5.5		
Gate Drain Charge	Q_{gd}			3.1		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=20V$ $R_L=1.0\Omega$ $R_{GEN}=3.0\Omega$		7.5		ns
Turn-On Rise Time	t_r			2		
Turn-Off Delay Time	$t_{d(off)}$			24		
Turn-Off Fall Time	t_f			3		

电参数曲线图 / Electrical Characteristic Curve

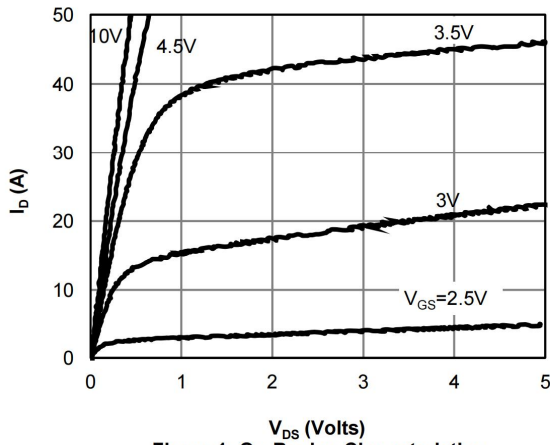


Figure 1: On-Region Characteristics

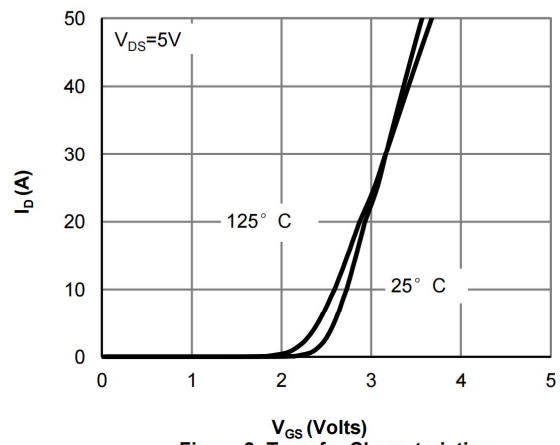


Figure 2: Transfer Characteristics

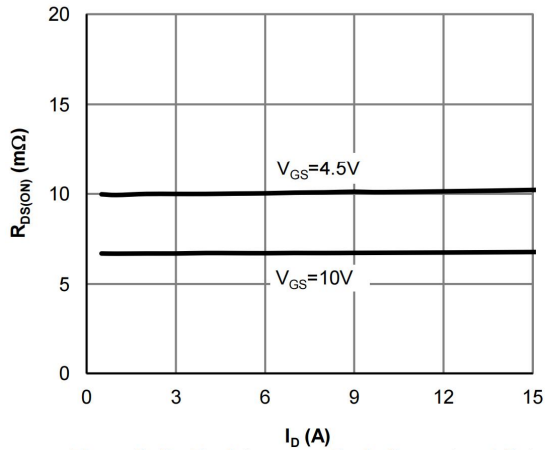


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

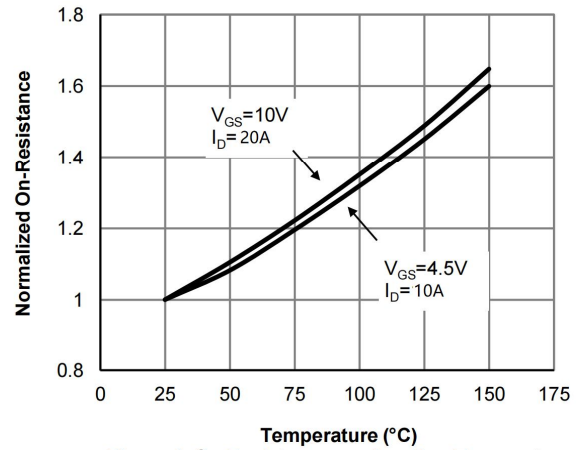


Figure 4: On-Resistance vs. Junction Temperature

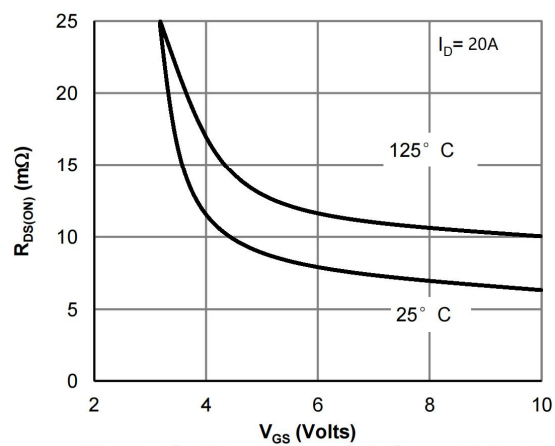


Figure 5: On-Resistance vs. Gate-Source Voltage

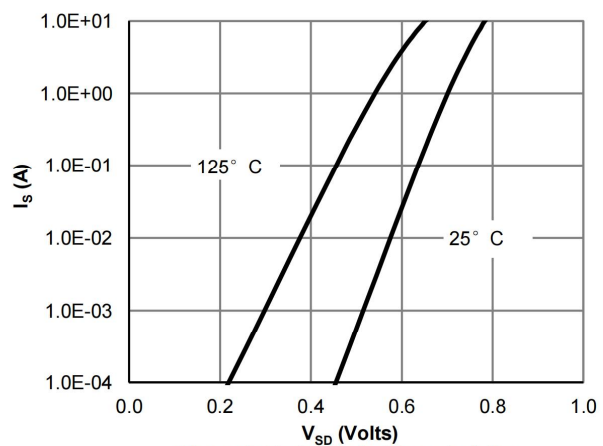


Figure 6: Body-Diode Characteristics

电参数曲线图 / Electrical Characteristic Curve

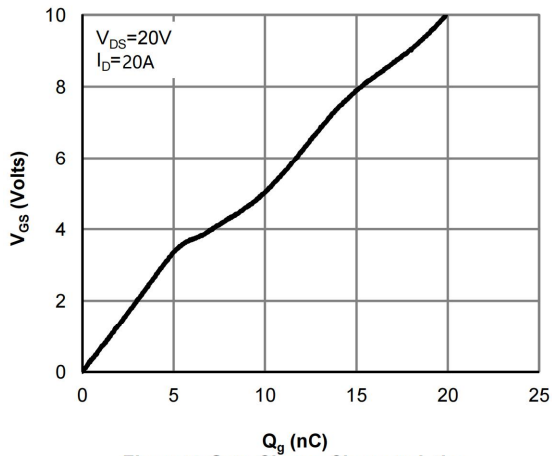


Figure 7: Gate-Charge Characteristics

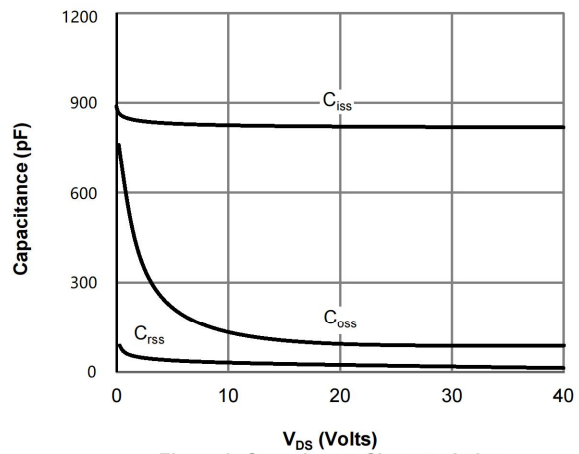


Figure 8: Capacitance Characteristics

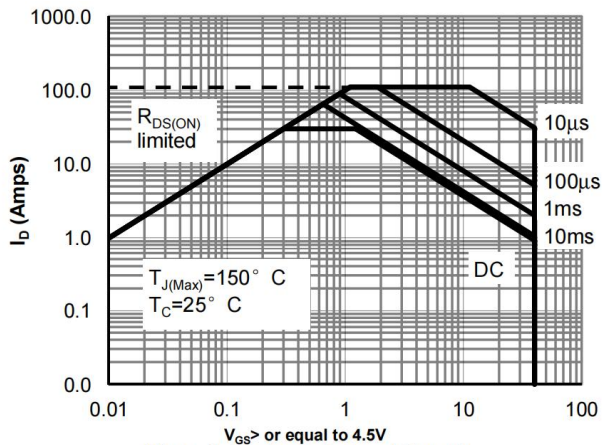


Figure 9: Maximum Forward Biased Safe Operating Area

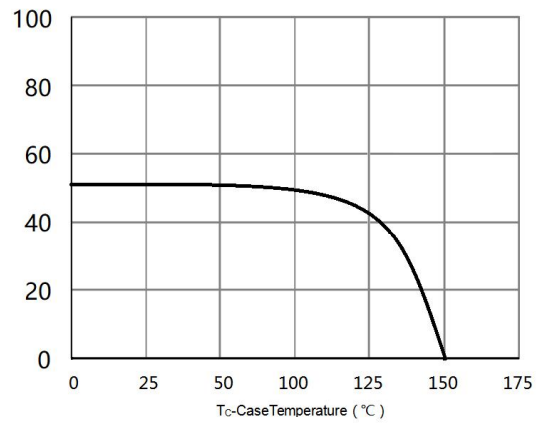


Figure 10: Maximum Continuous Drain Current Vs Case Temperature

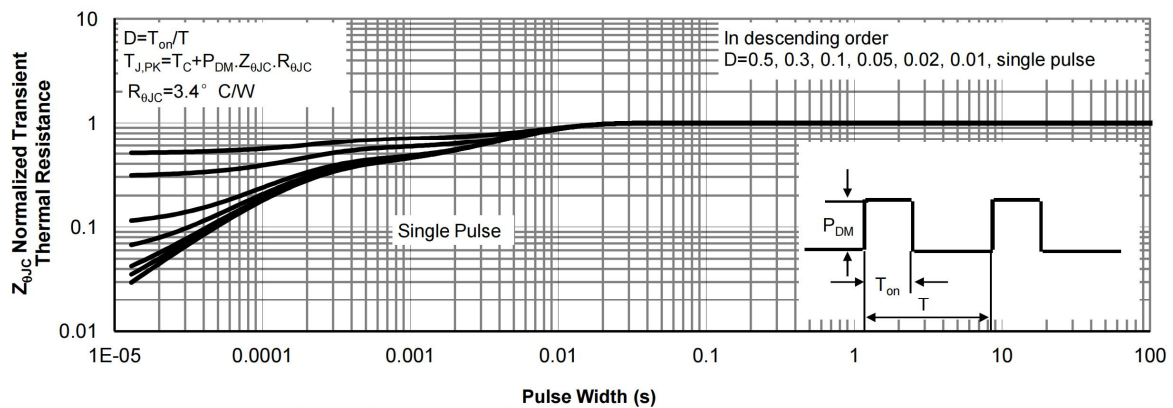
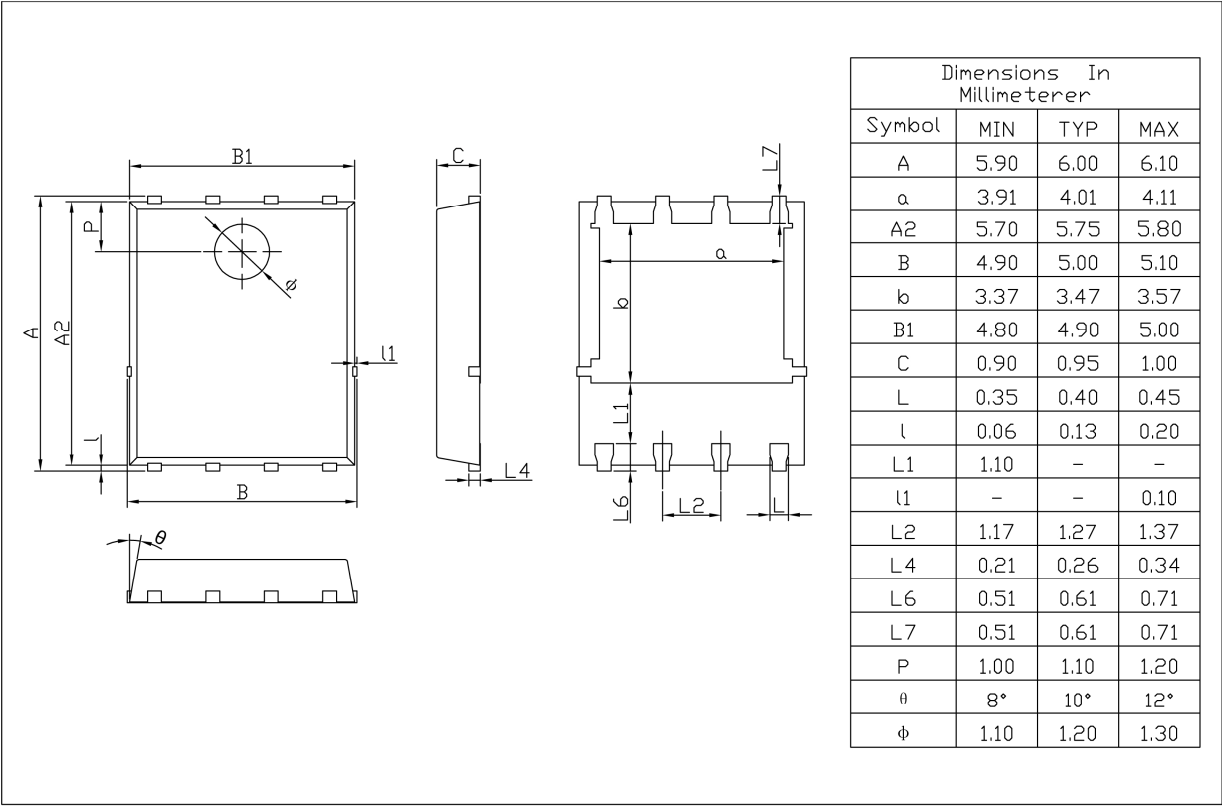


Figure 11: Normalized Maximum Transient Thermal Impedance

外形尺寸图 / Package Dimensions

PDFN5 X6

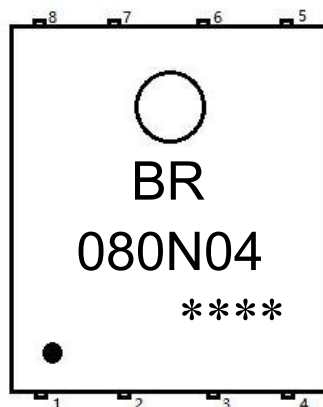
Unit:mm



Rev.00 201812



印章说明 / Marking Instructions



说明：

BR： 为公司代码

080N04： 为产品型号

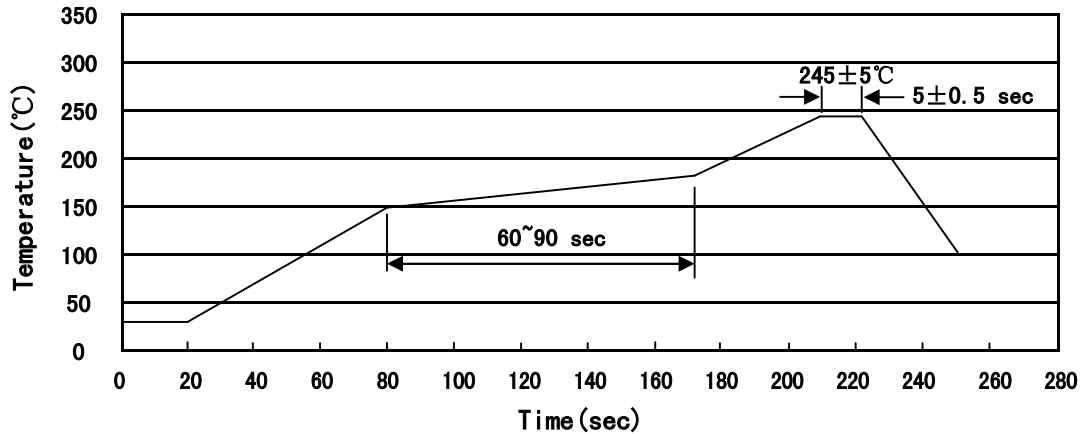
****： 为生产批号代码，随生产批号变化

Note：

BR： Company Code

080N04： Product Type

****： Lot No. Code, code change with Lot No

回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)


说明：

- 1、预热温度 150~180°C，时间 60~90sec；
- 2、峰值温度 245±5°C，时间持续为 5±0.5sec；
- 3、焊接制程冷却速度为 2~10°C/sec.

Note:

- 1.Preheating:150~180°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：260±5°C

时间：10±1 sec.

Temp.:260±5°C

Time:10±1 sec

包装规格 / Packaging SPEC.

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
PDFN5 × 6	5000	2	10000	6	60000	13" × 12	360 × 360 × 50	380 × 335 × 366

使用说明 / Notices